

Coherence and density dynamics of excitons in a single-layer MoS₂ reaching the homogeneous limit

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Abstract

We measure the coherent nonlinear response of excitons in a single-layer of molybdenum disulphide embedded in hexagonal boron nitride, forming a *h*-BN/MoS₂/*h*-BN heterostructure. Using four-wave mixing microscopy and imaging, we correlate the exciton homogeneous and inhomogeneous broadenings. We find that the exciton dynamics is governed by microscopic disorder on top of the ideal crystal properties. Analyzing the exciton ultra-fast density dynamics using amplitude and phase of the response, we investigate the relaxation pathways of the resonantly driven exciton population. The surface protection *via* encapsulation provides stable monolayer samples with low disorder, avoiding surface contaminations and the resulting exciton broadening and modifications of the dynamics. We identify areas localized to a few microns where the optical response is totally dominated by homogeneous broadening. Across the sample of tens of micrometers, weak inhomogeneous broadening and strain effects are observed, attributed to the remaining interaction with the *h*-BN and imperfections in the encapsulation process.

Keywords

MoS₂, 2D materials and heterostructures, coherent nonlinear spectroscopy, microscopy, four-wave mixing, exciton dephasing and disorder, ultrafast dynamics

Context. Transition metal dichalcogenides (TMDs) are lamellar compounds held together by van der Waals inter-layer interactions. For this reason, they can be exfoliated down to a single-layer (SL), similar to graphene obtained from graphite. Even though the inter-layer interactions are weak, they have an important effect on the band structure of TMDs, moving them towards an indirect band gap. When thinning bulk crystals down to SLs, many TMDs can be converted to a direct band gap semiconductor, as first shown for MoS₂. The discovery of efficient emission and absorption of light in SL TMDs, facilitated by creation of excitons (EXs) of high binding energy and their fast radiative recombination,^{1,2} made two-dimensional TMDs candidates for next generation optoelectronics. Additionally, the symmetry and chemical composition of the atomic lattice of TMDs enable, besides their flexibility and partial transparency, a wealth of innovative application concepts.³⁻⁷

Among semiconducting TMDs, MoS₂ has been the most studied, because of its expected superior stability in atmospheric conditions. Several recent observations nevertheless challenge this expectation. The measured EX linewidth has been on the order of several tens of meV even at low temperatures.^{4,6-12} These high values indicate an inhomogeneous broadening (σ) of the EX transition more than an order of magnitude above the homogenous broadening (γ) expected in the meV range.¹³ The dominating inhomogeneities ($\sigma \gg \gamma$) in SL MoS₂ conceal the intrinsic properties of the EXs resulting from the underlying band structure, which is still under debate.¹⁴⁻¹⁶ Presumed origins of σ observed in the experiments down to low temperature are adsorbed impurities and crystal defects such as vacancies, strongly affecting the quantum yield.^{17,18} Another source of inhomogeneous broadening is the substrate onto which the two-dimensional material is typically deposited. The most common substrate used to fabricate optoelectronic devices, a thin thermal oxide (silica) layer on silicon wafers, is known to be corrugated and to contain charged impurities, generating a disorder potential landscape for EXs in the supported TMD layer.

Recently, deterministic transfer methods,¹⁹ developed to stack two-dimensional materials in the form of so-called van der Waals heterostructures,²⁰ have been applied to prepare MoS₂ SLs sandwiched between two thin hexagonal boron nitride (*h*-BN) layers.^{13,21,22} In these structures, the distance between MoS₂ and the charged impurities in SiO₂ and possible adhered impurities on the top surface is set by the respective *h*-BN thicknesses and is typically several tens of nanometers (nm). Moreover, the van der Waals interaction is thought to promote a close, conformal and very flat contact at the MoS₂/*h*-BN interface (with typically few Å interfacial distances²³) by expelling adsorbed molecules sideways, much like a flat-iron would eliminate the pleats of a clothing. In such samples, photoluminescence (PL) revealed sharp excitonic features of a few meV width, approaching the expected homogenous limit.¹³ The narrow emission allowed to deepen the understanding of the excitonic complexes involving different valleys¹³ and to observe the EX's excited states²² in MoS₂ SLs. The

encapsulation strategy has also been employed to reduce σ in other TMDs.^{21,24-26}

Rationale and methodology. The question arises if σ could be suppressed with this method sufficiently to provide a dominating radiative broadening and a resulting long-range exciton-polariton formation. Towards this, can one show correlations between γ and σ ? Such fundamental issues are relevant for spectroscopists and material scientists exploring optical properties of TMD SLs and, in a broader context, for condensed matter physicists investigating two-dimensional systems. We note that the EX spectral line-shape measured in linear transmission or reflection^{13,21,22} is a convolution of γ and σ . Separating them, for example by applying line-shape fits such as a Voigt profile, requires the prior knowledge of homogeneous and inhomogeneous line-shapes. For example, in the limit $\sigma \gg \gamma$, the lineshape is Gaussian, such that γ cannot be reliably estimated. Interestingly, the EX emission measured in non-resonantly excited PL can show narrower linewidths than those retrieved *via* resonant absorption. This can be understood as due to the carrier and EX relaxation selecting local potential minima at low temperatures, prior to EX recombination.

To separate homogeneous from inhomogeneous broadening in the EX line-shape, nonlinear spectroscopy, specifically four-wave mixing (FWM), is particularly suited. FWM driven on an inhomogeneously broadened optical transition - for example created by a spatially varying EX transition in TMDs - forms a photon echo.²⁷⁻²⁹ Its temporal width is determined by σ , assuming that the excitation pulses are sufficiently short with respect to \hbar/σ . Conversely, its amplitude decay with delay time between the first two exciting pulses, *i. e.* τ_{12} , is only due to the microscopic EX dephasing. In case of a simple exponential decay it determines the full width at half maximum (FWHM) of the homogeneous linewidth $\gamma = 2\hbar/T_2$, where T_2 denotes the EX dephasing time. Only in the case of vanishing σ , the latter can be read from the FWM transient, taking the form of a free induction decay, overcoming the necessity to scan τ_{12} . This however is only known *a posteriori*. Since the inhomogeneous broadening is due to the spatial variation of the EX energy on the scale of its radius of a few nm, it can also vary on longer scales spatially across the sample surface. Furthermore, since also the homogeneous broadening is depending on this spatial variation, the measured pair (σ, γ) is a spatially varying quantity on a length scale with a lower limit given by the size of the sample region probed by the optical excitation, and an upper limit given by the size of the investigated sample. The spatial variations across the flake can be due to strain from the substrate or encapsulating layers,³⁰ the dielectric environment, the density of impurities and defects, and the free carrier concentration. These mechanisms give rise to the disorder, affecting EXs' radiative rates,³¹ and thus γ . The disordered potential landscape results in varying EX localization lengths and produces different sets of EX energy levels,³² determining σ and affecting a population lifetime T_1 .

Enhanced spatial and temporal resolution is required to experimentally investigate the above issues. It is thus instructive to study TMD SLs with FWM micro-spectroscopy, resolving the signal on a 100 femto-second (fs) time and 300 nm spatial scale.^{28,29} In the employed implementation, the exciting laser pulses propagate co-linearly in the same spatial mode, while the signal is discerned *via* optical heterodyning. This technique allows us to spatially resolve σ and γ , revealing correlations between EX's dephasing and σ . The signal to noise in this experiment is increased compared to more traditional two-dimensional systems, such

as GaAs quantum wells, by the large oscillator strength μ of EXs in MoS₂ SLs. The latter generates substantial multi-photon nonlinear responses,^{33,34} including FWM as its amplitude (intensity), scales as μ^4 (μ^8), respectively.

Results. In this work, we report FWM microscopy of two heterostructures composed of a SL MoS₂ flake encapsulated by layers of a high quality *h*-BN.³⁵ Details regarding sample fabrication are provided in the *Methods* section. In contrast to MoSe₂,²⁸ WSe₂ and WS₂,²⁹ SLs, we find that encapsulation is essential to observe a strong, coherent, nonlinear optical response in exfoliated MoS₂ SLs. By analyzing the FWM transients acquired in the first investigated sample which exhibits more disorder (sample A), we assess homogeneous and inhomogeneous contributions to the EX spectral line-shape. We find that the encapsulation leads to a global reduction of σ , down to a few meV, comparable to the homogeneous broadening. In some micron sized areas of the sample, a decrease of σ correlated with an enhanced FWM signal can be observed. We exploit the varying inhomogeneous broadening across the sample to investigate the impact of EX disorder onto their coherence dynamics, occurring at a pico-second (ps) time scale. The retrieved correlations between σ , γ , μ and T_1 provide fundamental insights into EX localization and dynamics in a disordered two-dimensional landscape. Using the second sample, with significantly less disorder (sample B), we demonstrate the EX optical response in its homogeneous limit. In such conditions, we assess the phonon-induced homogeneous broadening with increasing temperature. We then evaluate the excitation-induced dephasing with increasing EX density. Finally, the dynamics of the EX density after resonant excitation is unveiled. On a picosecond time scale we resolve an initially dominating radiative decay,^{28,36} competing with non-radiative redistribution into optically dark states. The remaining EX density is scattered back to the optically bright EXs states and recombines (radiatively and non-radiatively) assisted by a three-exciton decay process visible on a nanosecond timescale. The coherent detection allows to disentangle the EX populations in the different bright and dark states. They create a different phase of the response depending on the phase of the complex EX renormalization of the optically probed bright EXs due to Coulomb and exchange interaction with the total EX density. These contributions involve different EX populations, each corresponding to charge carriers in the inequivalent K and K' valleys of the electronic band structure.³⁷ For example, broadening described by an imaginary part of the interaction is in quadrature with energy shifts described by the real part of the interaction. The different relaxation processes contribute to the FWM amplitude with different phases, imprinting unusual signatures in the measured density dynamics of the FWM amplitude due to constructive and destructive interferences.³⁷

Characterization with linear spectroscopy. The optical pictograph of the sample A, containing an elongated MoS₂ SL, displayed in Figure 1a (left), shows breaks (indicated by orange arrow) and wrinkles (red arrow) in the flake, as well as air trapped in bubbles and puddles²³ (yellow arrow). In spite of these features, structurally clean areas extending across about (7x7) μm^2 are found, such as the one enclosed with a white dashed-contour. For the initial characterization at T=5 K, we perform hyperspectral imaging of the confocal PL (non-resonantly excited with a CW laser diode operating at 450 nm, $\sim 10 \mu\text{W}$ arriving at the sample) across the spectral range around the EX emission. The experiment reveals

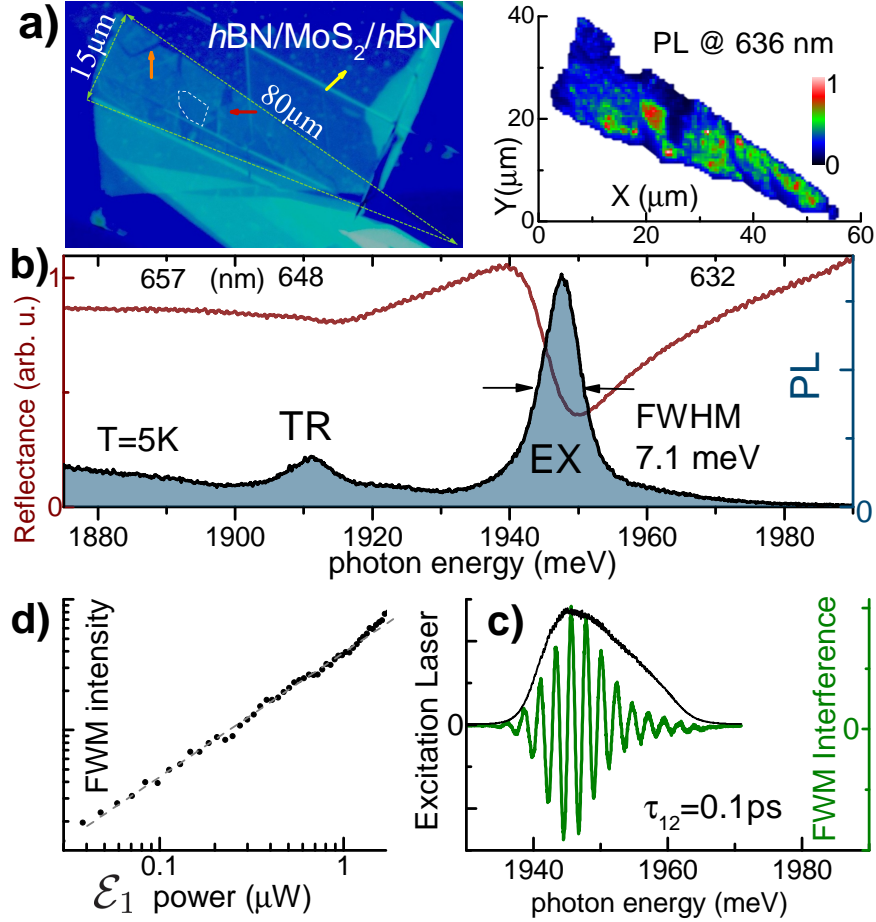


Figure 1: **Optical response of the sample A, composed of a MoS₂ SL embedded in between layers of h-BN.** (a) Right: Spatial mapping of the confocal photoluminescence intensity (PL) at (636 ± 0.5) nm. Left: Microscope image of the sample under the white light illumination in reflection. The green dashed line indicates the position of MoS₂ flake with a large extension of several tens of micrometers. Reflectance and PL measured in the area encircled with a dashed line are given in (b). (c) Typical FWM spectral interferogram measured at the EX transition (green). The excitation intensity spectrum of the femtosecond laser is given in black. (d) FWM intensity dependence of the excitation power (in a two-beam configuration) showing the expected linear dependence with the pump \mathcal{E}_1 power. \mathcal{E}_2 power was fixed around $4 \mu\text{W}$.

EX center energies spanning across 30 meV, with a PL intensity varying over more than an order of magnitude and different proportions of neutral (EX) and charged (trion, TR) states, as shown in Supplementary Figure S1. We also see zones, where both PL and reflectance of EX are suppressed, while a characteristic spectrally broad band,²¹ that was tentatively attributed to defects, appears below the EX energy. A spatial map of the PL intensity across the entire flake for (636 ± 1) nm is shown in Figure 1 a (right). Within this region we identify areas containing quite narrow EX emission, down to 7.1 meV FWHM, as exemplified in Figure 1 b.

To inspect the linear coherent response, we performed micro-reflectance from the same zone, showing resonances at EX, TR, as well as the B exciton, centered at ~ 587 nm (not shown). In spite of the substantial improvement of the optical response with respect to previously examined free-standing MoS₂ SLs,^{13,38} the EX line-shape in this *h*-BN/MoS₂/*h*-BN heterostructure is still affected by σ . To disentangle σ and γ we employ three-beam FWM microscopy, inferring EX coherence and population dynamics from femtosecond to nanosecond timescales.

Coherence dynamics *via* four-wave mixing microscopy. The FWM microscopy was performed in the configuration reported in Ref. [29], briefly described in the *Methods* section. A typical spectral interferogram of the two-beam FWM field (proportional to $\mathcal{E}_1^* \mathcal{E}_2 \mathcal{E}_2$ where $\mathcal{E}_{1,2}$ are the fields of the exciting pulses) from the neutral EX in our heterostructure is presented in Figure 1 c (green trace). The measured spectrally integrated FWM intensity (amplitude squared) as a function of the power of the first arriving pulse (\mathcal{E}_1), given in Figure 1 d, shows a linear dependence, consistent with the third order regime of the FWM, up to 1 μ W. The latter corresponds to an excited EX density of around 10^9 cm⁻² per pulse, which is around four orders of magnitude below the EX saturation density in TMDs.

We now turn to the assessment of σ and γ by inspecting the time-resolved FWM amplitude as a function of τ_{12} . The experimental results are given in Figure 2 (left). In panel a) we see that FWM is observed for $\tau_{12} > 0$, and already for $\tau_{12} > 0.2$ ps takes a form of a Gaussian pulse centered close to $t = \tau_{12}$, *i. e.*, the photon echo is formed. In an ideal case of a set of two-level systems and for delta-pulses, the FWM signal for $\tau_{12} > 0$, $t > 0$ can be described by a product of an exponential decay and a Gaussian shifting its maximum in time: $|\text{FWM}(t, \tau_{12})| \propto \exp[-\tau_{12}/T_2] \exp[-\nu^2(t - \tau_{12})^2/2]$. The echo has a constant temporal width, with a standard deviation of $1/\nu$ and FWHM of $\sqrt{8 \ln 2}/\nu$. This quantity is linked with the FWHM of the spectral inhomogeneous broadening as $\sigma = \sqrt{8 \ln 2} \hbar \nu$. Conversely, the amplitude decay of the echo with increasing τ_{12} reflects the homogeneous dephasing time $T_2 = 2\hbar/\gamma$. The measured signal is convoluted with the temporal duration of the applied pulses of about 150 fs, which is taken into account in the modeling presented in Figure 2 b. The two-dimensional fit to the experimental data shown in a) yields $(\gamma, \sigma) = (2.10 \pm 0.03, 12.5 \pm 0.2)$ meV. We note that the FWM amplitude at pulse overlap ($\tau_{12} = 0$), encoded in the hue level, principally reflects the EX oscillator strength μ .

In order to discuss the local character of the quantities (γ, σ, μ) , let us now consider Figure 2 e, where the FWM transient acquired within a distance of a few μ m from the spot considered in a) is shown. Here, the shape of the photon echo is different in several respects: i) it is broader in real time, showing that σ is smaller, ii) the amplitude decay along τ_{12} is

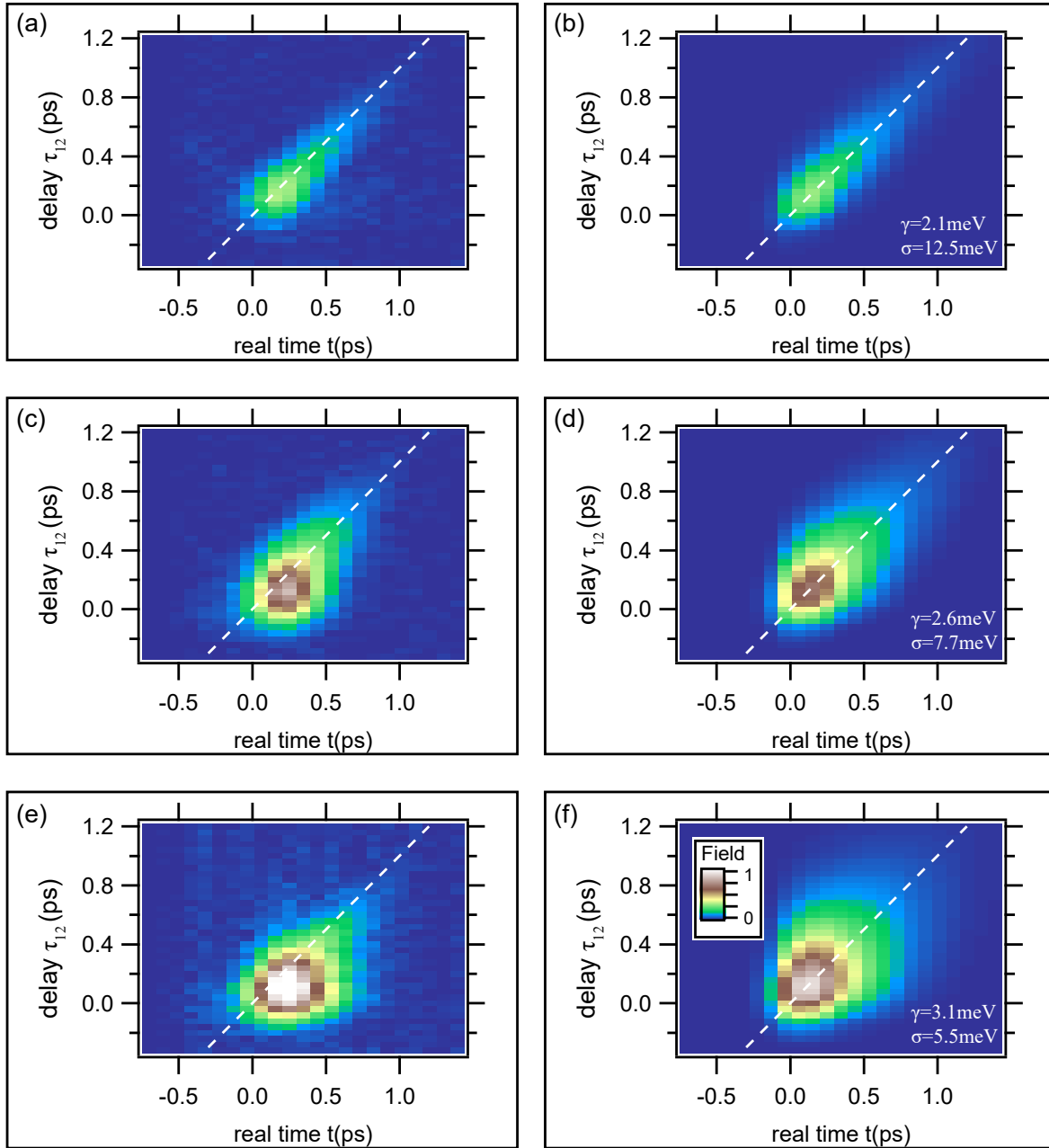


Figure 2: **FWM micro-spectroscopy** carried out on sample **A**. (a, c, e) Time-resolved FWM amplitude for different delays τ_{12} at $T=5\text{K}$, showing formation of the photon echo. The disorder is decreasing from top to bottom, quantified by the increase of γ and decrease of σ . (b, d, f) are corresponding simulations.

faster, revealing a shorter T_2 (and thus larger γ), iii) The amplitude around $\tau_{12} = 0$ is larger by an order of magnitude, showing a larger μ . These changes are quantified by the fitted form of the echo, given in Figure 2f with the parameters $(\gamma, \sigma) = (3.10 \pm 0.08, 5.5 \pm 0.3)$ meV at this position. It is worth to note that the response in e) already deviates from the echo form, *i. e.* the maximum of the signal is not aligned along the diagonal, indicating a transition to a homogeneously broadened case. When further approaching this limit, the coherence dynamics displays a crossover from the photon echo towards the free induction decay, resulting in the bi-exponential decay, as discussed in the Supplementary Figure S2. In Figure 2c, we present another case of the measured echo, with the intermediate line-shape parameters $(\gamma, \sigma) = (2.60 \pm 0.07, 7.7 \pm 0.3)$ meV, as reflected by the simulation shown in the panel d). These examples demonstrate that the EX optical response is affected by the disorder on scales above and below the resolution of the present experiment, 300 nm. Below this resolution, the disorder leads to an effective inhomogeneous broadening of the response, and a reduction of the radiative decay rate by the localization of the EXs below the optical resolution $\lambda/2$, thus leading to a mixing of dark EX states outside the radiative cone. Above this resolution, we can see the varying impact of disorder acting on EXs, as shown in the three examples.

To verify if the encapsulation can be used to virtually eliminate σ , we have processed a second heterostructure (sample B), presented in the Supplementary Figure S3. To exclude any aging issues, the FWM experiment was started only a few hours after completing the fabrication. At micron-sized areas we measure FWM amplitude as narrow as 4.4 meV (FWHM) at $T=4.5$ K, as shown by filled-blue peak in Figure 3a. No signatures of the photon echo can be noticed, when inspecting FWM transients *versus* τ_{12} . Thus, here σ is not detectable and the broadening reaches its homogeneous limit. In that limit, time-resolved FWM takes a form of a free induction decay (FID), *i. e.*, exponential decay from $t = 0$ for any $\tau_{12} > 0$, with a decay constant determined by T_2 , as depicted by a scheme framed in b). Two explicit examples of the measured FID at 4.5K for $\tau_{12} = 0.04$ ps (yellow arrow) and $\tau_{12} = 0.6$ ps (orange arrow) are given by the yellow and orange points in a). By deconvoluting the laser pulse duration we retrieve $T_2 = (320 \pm 20)$ fs, *i. e.*, $\gamma = 4.11$ meV, close to FWHM of the spectrally resolved amplitude, also in a stunning agreement with γ retrieved from time-integrated FWM as a function of τ_{12} , shifting the focus of the discussion to b). Interestingly, therein at 4.5 and 10 K we clearly detect the signal at negative delays with a FWM rise time of around 130 fs (after deconvoluting the pulse duration), close to theoretical prediction³⁹ of $T_2/2$. Such contributions have previously been observed when studying homogeneously broadened EXs in GaAs quantum wells and were assigned to the local-field effect.³⁹

A relevant factor influencing the EX coherent dynamics is the temperature, which determines the density of acoustic and optical phonons.⁴⁰ Increasing the temperature, and thus the phonon density, broadens γ by phonon-assisted scattering.^{27-29,41} On the other hand, the changing phonon-scattering influences the EX relaxation dynamics.³⁷ To measure the impact of temperature on γ , we plot in Figure 3b the EX coherence dynamics, *i. e.*, the time-integrated FWM amplitude as a function of τ_{12} , for different temperatures. At this homogeneously broadened zone the FWM amplitude decays as $\exp(-\tau_{12}/T_2)$. With increasing temperature from 5 K to 70 K, we measure shortening of the dephasing time, and thus an increase of the homogeneous broadening from 4 to 23 meV, as marked by violet squares in c). In parallel, virtually the same broadening is seen in the FWM spectral amplitudes

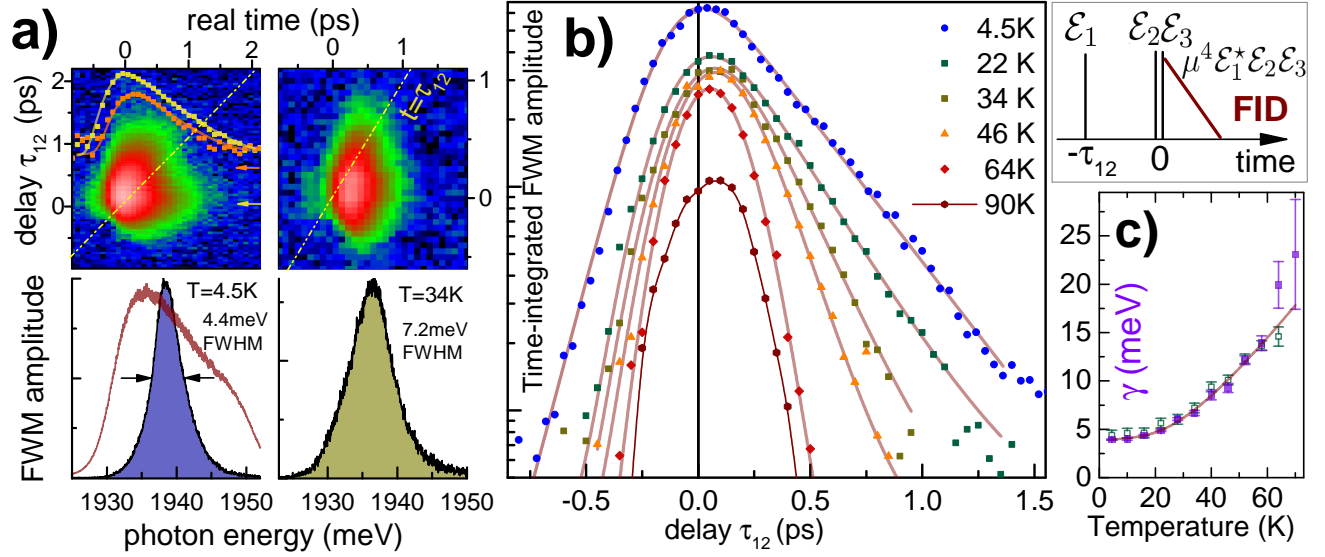


Figure 3: **Exciton's coherence dynamics in a MoS₂ heterostructure exhibiting low disorder (sample B), measured at different temperatures.** (a) Top: FWM transients *versus* τ_{12} at $T=4.5\text{K}$ and 34K showing FWM free induction decay, thus proving EX broadening in its homogeneous limit. Bottom: corresponding FWM spectra measured for $\tau_{12} = 0.5\text{ps}$ directly showing the temperature-induced broadening. Red trace in the bottom-left panel is the spectral shape of the reference pulse \mathcal{E}_R . (b) Time-integrated FWM amplitudes as a function of τ_{12} measured for temperatures as indicated. The dephasing time T_2 is measured from the exponential decay at $\tau_{12} > 0$, an increasing influence of the phonon dephasing is observed when increasing the temperature. At 4.5K (blue circles) note the presence of the FWM signal for $\tau_{12} < 0$. Frame: a scheme of the three-pulse FWM rephasing sequence employed to assess the coherence dynamics, τ_{23} is set to zero in the experiment. In the homogeneous limit ($\gamma \gg \sigma$) of the EX broadening, FWM transient is a free induction decay (FID) instead of the photon echo. (c) Temperature dependence of γ retrieved from b) (violet squares) compared with the spectral FWHM of the FWM amplitude (open green squares). Red curve is the fit to experimental data (see main text).

(green open squares): To directly illustrate the dominance of the homogeneous broadening mechanism through phonons at this sample position, in the bottom-right panel of a) we present the data measured at 34 K. At higher temperatures, as exemplified for 90 K, the dephasing is too fast to be measured with our current setup, limited by the temporal resolution of around 150 fs. We fit the data with a sum of a linear and exponential activation terms: $\gamma(T) = \gamma_0 + aT + b/[\exp(E_1/k_B T) - 1]$. For the linear term, attributed to acoustic phonons, we obtain $[\gamma_0 = (3.78 \pm 0.15) \text{ meV}, a = (0.03 \pm 0.01) \text{ meV/K}]$. For the second term we find: $[b = (35 \pm 12) \text{ meV}, E_1 = (8.3 \pm 1.5) \text{ meV}]$. In contrast to previously inspected SL TMD,^{28,29} the value of activation E_1 is here not consistent with the energy of optical phonons⁴⁰ of around 35 meV. We tentatively link such a more pronounced temperature dephasing with a particularly small conduction band splitting in MoS₂, favoring the population loss of bright excitons through their scattering to dark states.

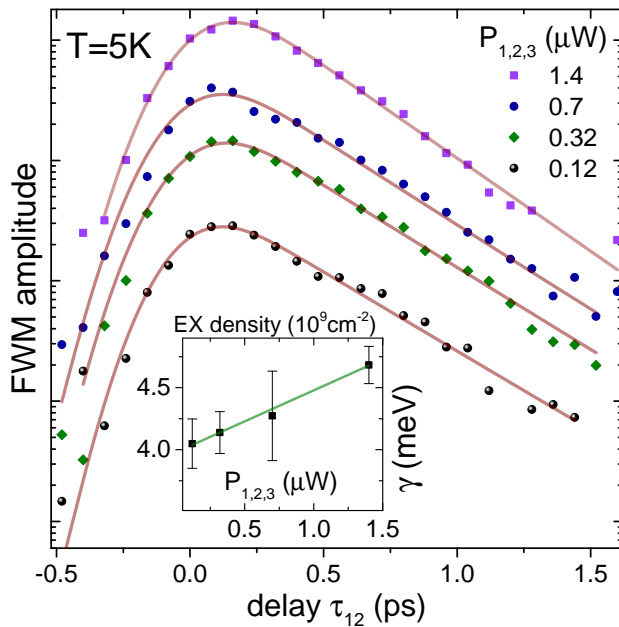


Figure 4: **Exciton’s coherence dynamics in a MoS₂ heterostructure exhibiting low disorder (sample B), measured at different excitation powers.** A stronger slope of the dephasing curves with increasing $P_{1,2,3}$ is due to excitation-induced dephasing. Within our range of $P_{1,2,3}$ we measure increase of γ by 0.5 meV when rising the EX density by an order of magnitude.

While investigating dephasing mechanisms in TMD SLs, it is also instructive to determine the impact of EX-EX interactions on γ . Such interactions cause the broadening²⁷ of γ by 250% when increasing the EX density from 10^{10} to 10^{11} cm^{-2} . In Figure 4 we present dephasing curves measured for different excitaton powers $P_{1,2,3}$, spanning across typically operating excitation range in our experiments. With increasing EX density from around 10^8 to 10^9 cm^{-2} , we detect a small, but measurable increase of the homogeneous broadening by 15%; 0.5 meV over an order of magnitude density. As the absorption (thus also EX density for a fixed $P_{1,2,3}$) could vary across the flake, it is important to check that such excitation-induced dephasing is of minor importance in the applied range of $P_{1,2,3}$: Values of γ retrieved

from the analysis of the spatially-resolved FWM experiment, presented in the next section, are expected not to be significantly affected by spatially fluctuating EX-EX interactions.

Four-wave mixing mapping and statistical correlations. To draw a comprehensive picture of the balance between the microscopic disorder and the EX coherent dynamics we go back to the more disordered heterostructure (sample A, Figure 1). We use FWM imaging,²⁹ measuring photon echos, as in Figure 2, at the grid of spatial points of the sample. For each position, we perform two-dimensional measurements and fits as in Figure 2, extracting γ , σ and the FWM amplitude, μ^4 . While we note that these fits are not taking into account the interaction induced nature of the signal, the resulting parameters mimic the response well and are suited for $\sigma \gg \gamma$, being the case for the investigated sample. These parameters are presented as color maps in Figure 5 a-c. Within the investigated area, γ (FWHM) spans from 1.8 to 4.3 meV. We see the spread of σ (FWHM) from 4.7 to 16 meV, with the less disordered zone colored in green-blue in Figure 5 a. Note that the upper limit of the measured σ is set by the spectral width of the excitation laser. This low-disorder zone (greenish area) also shows the strongest FWM amplitude, proportional to μ^4 , as shown in Figure 5 b.

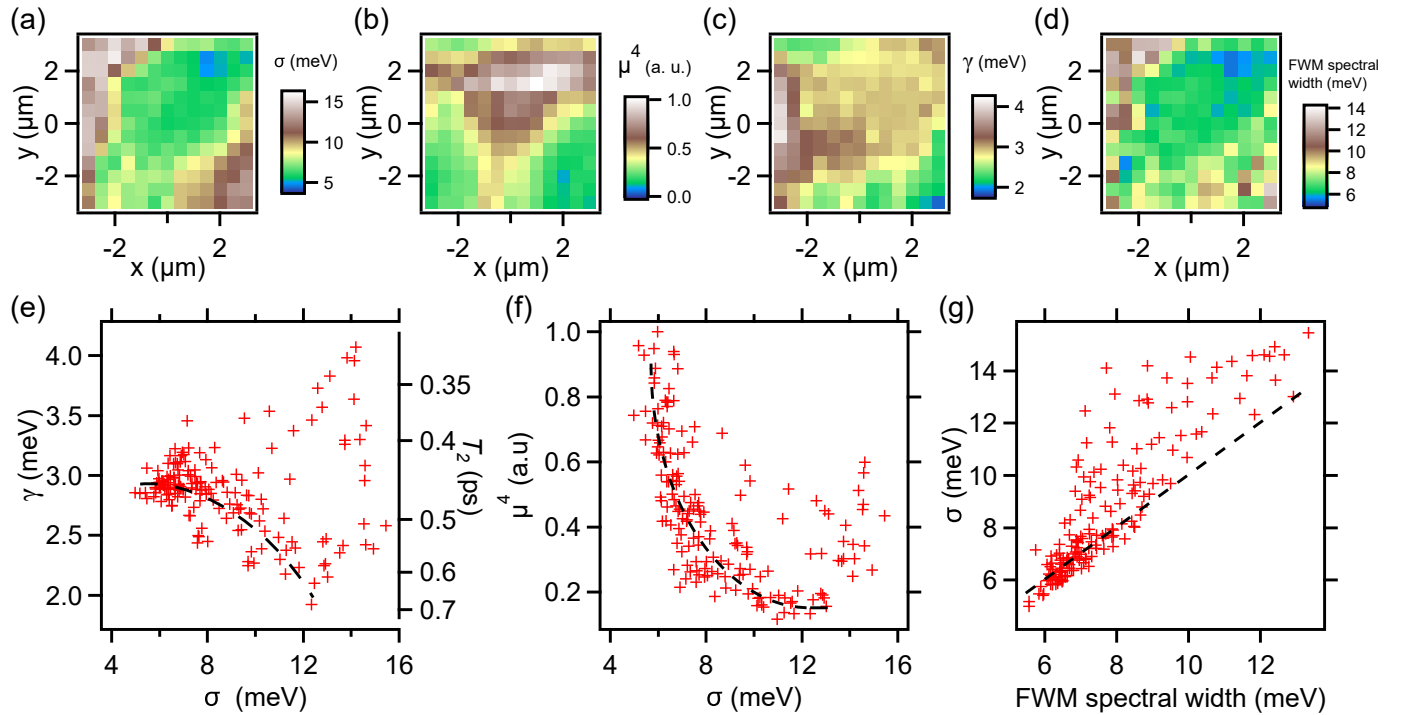


Figure 5: **Four-wave mixing spatial imaging, sample A.** (a, b, c) Mapping of the homogeneous broadening γ , the inhomogeneous broadening σ , and of the FWM amplitude at $\tau_{12} = t = 0$ corresponding to μ^4 . The areas of the weakest disorder yield the smallest σ , the shortest T_2 and largest γ , as summarized in (e). Dashed lines in (e) and (f) are guides to eye. (d) Mapping of σ retrieved from fitting the spectrally resolved FWM with a Gaussian profile. (f) Correlation between the FWM amplitude measured at $\tau_{12} = t = 0$ and σ . (g) Correlation between spectral FWM broadening and σ (as retrieved from the FWM delay-and-temporal dynamics) is visible. The diagonal is drawn with the dashed line.

A pronounced correlation between μ^4 and σ is explicit in Figure 5 f. It is interpreted as follows. Smaller σ signifies weaker disorder enabling larger EX center-of-mass localization lengths,³² thus generating large EX coherence volume in real space. In the reciprocal space, the EX wavefunction is thus dominated by small k-vector components and therefore is better contained within the light cone. This increases the light-matter interaction, and thus also μ , resulting in an enhancement of the FWM signal. Instead, at areas showing large σ , the EX spans more prominently out of the light cone. Smaller overlap with the light-cone results in decreasing μ and increasing radiative lifetime: instances of such qualitative dependencies between μ , σ and T_1 are shown in the Supplementary Figure S4. Close to the radiative limit ($T_2 = 2T_1$), this implies an increase of T_2 and thus a decrease of the homogeneous linewidth γ with increasing σ . Such a correlation is visible in Figure 5 e. Nonetheless, we do observe points showing a short T_2 and yet a large σ . This is attributed to other homogeneous broadening mechanisms, such as non-radiative exciton-electron scattering, which vary across the investigated area.

It is instructive to compare the parameters obtained through the temporal dynamics with the ones from the spectra. In Figure 5 d we present the inhomogeneous width (FWHM) of the Gaussian profiles we fit to the spectrally-resolved FWM data. We find agreement between the inhomogeneous width determined by the FWM transients (a) and the spectral FWHM (d) - the correlation between both is shown in g). In the Supplementary Figure S5 we further exploit correlations and demonstrate that σ , characterizing amount of disorder, increases with the EX center energy, obtained from the spectra. This means that the short-range (sub-resolution) disorder is dominating within the probed region and is of repulsive nature.

Population dynamics on a nanosecond scale. After the resonant excitation several relaxation mechanisms play an important role.³⁷ They are governed by, on the one hand, the high oscillator strength⁴² and thus fast radiative recombination rate, and on the other hand, by the EX conversion towards different dark states, resulting from the peculiar valley structure and available scattering channels with phonons, charge carriers and EXs. Due to this scattering and radiative recombination, the EX phase is lost on a picosecond timescale, as shown by the results discussed in the previous sections. Nonetheless, the EX population in the dark states is evolving on a much longer timescale. Time-resolved PL performed on TMD SLs typically shows tails in a range of a few 100 ps.⁴³⁻⁴⁶ The quantitative interpretation of PL dynamics is difficult, as there are many intermediate states in the scattering pathway from the initially excited electron-hole pairs to the emission of the bright EX states. Importantly, the occupation of dark EX states is not directly observable, but can be inferred indirectly, by modeling. Conversely, the experiments using phase-sensitive heterodyne detection^{28,37} are sensitive not only to the bright EXs, but also the dark ones, through their interaction with the optically probed bright EXs. Even more, the phase of the signal encodes the phase of the complex interaction energy, enabling the distinction between population of different dark state reservoirs (fast direct spin-allowed, direct spin-forbidden, indirect spin-allowed, and indirect spin-forbidden).³⁷ Furthermore, resonant pumping generates a well-defined initial density of bright EXs (within the light cone) with a given spin-state encoded by the light helicity. Namely, the two pulses \mathcal{E}_1 and \mathcal{E}_2 (shifted by the radio-frequencies, Ω_1 and Ω_2 ,

respectively), arriving in time overlap, create an EX density $\mathcal{E}_1^* \mathcal{E}_2$, oscillating at the frequency $\Omega_2 - \Omega_1 = 1$ MHz (see *Methods*). The FWM signal probing the density dynamics - generated by the third pulse \mathcal{E}_3 delayed by τ_{23} - infers the amplitude and the phase of the resulting modulation of the excitonic response. This pulse sequence is shown in Figure 6 together with a typical dynamics measured at $T=5$ K.

Qualitatively, the data for different densities and temperatures, as presented for FWM amplitudes in the Supplementary Figure S6, are consistently described by:

1. A weak signal for negative times due to previous pulses (repetition period is 13 ns), about one order of magnitude below the signal at $\tau_{23} = 0$.
2. A signal amplitude rise from the negative delays τ_{23} , given by the pulse autocorrelation, accompanied with a $-\pi/2$ phase shift.
3. A decay of the amplitude to less than half its value occurring for $0 < \tau_{23} < 1$ ps.
4. Subsequently, the signal amplitude rises on a timescale of 10 ps, accompanied by a phase shift of about $\pi/2$.
5. For $\tau_{23} > 10$ ps the amplitude decays, following a power law up to a time of about 1 ns, while the phase shifts by about $-\pi/2$.

While the initial FWM decrease is attributed to the EX radiative recombination with the time constant given by τ_1 and simultaneous scattering to the dark states, its subsequent rise (with additional features developing when increasing the temperature, see Figure S6) is surprising. To interpret the density dynamics measured with the heterodyne FWM, we recall that the technique retrieves response functions which are complex, hence is sensitive to both amplitudes and relative phases of the components of the signal R . This permits signals stemming from different densities and different interaction processes (between different EX states) to interfere, which is visible when their relative contributions change along the delay τ_{23} . In the present case, this effect is pronounced, indicating that the dynamics contains EX densities with interaction energies of significantly different phases, so that a description using a constant phase fails. In particular, to describe our data set, we introduce the following complex response function:

$$\begin{aligned}
R(\tau = \tau_{23}) = & A_{\text{of}} \exp(\varphi_{\text{of}}) + \left\{ A_{\text{nr}} \exp\left(i\varphi_{\text{nr}} - \frac{\tau^2}{\tau_0^2}\right) \right. \\
& + \left[\sum_n A_n \left(\frac{1}{e^{\frac{\tau}{\tau_n}} - 1} + \frac{1}{2} \left(1 + \operatorname{erf}\left(\frac{\tau}{\tau_0} - \frac{\tau_0}{2\tau_n}\right) \right) \right) \right] \times \exp\left(i\varphi_n + \frac{\tau_0^2}{4\tau_n^2} - \frac{\tau}{\tau_n}\right) \\
& \left. + A_p \exp(i\varphi_p) \left[(1 + \gamma_p T_r)^{-\alpha} + \frac{1}{2} \left(1 + \operatorname{erf}\left(\frac{\tau}{\tau_0}\right) \right) \right] \right\} (1 + |\gamma_p \tau|)^{-\alpha} \quad (1)
\end{aligned}$$

The meaning of the parameters is explained in Table 1. The response function includes a complex offset ($A_{\text{of}}, \varphi_{\text{of}}$), a two-photon absorption process ($A_{\text{nr}}, \varphi_{\text{nr}}$) generating nonresonant FWM around $\tau_{23} = 0$ and exponential decay processes, all multiplied by the power law decay. Note that (A_n, φ_n) pairs represent amplitudes and phases for the density scattering processes

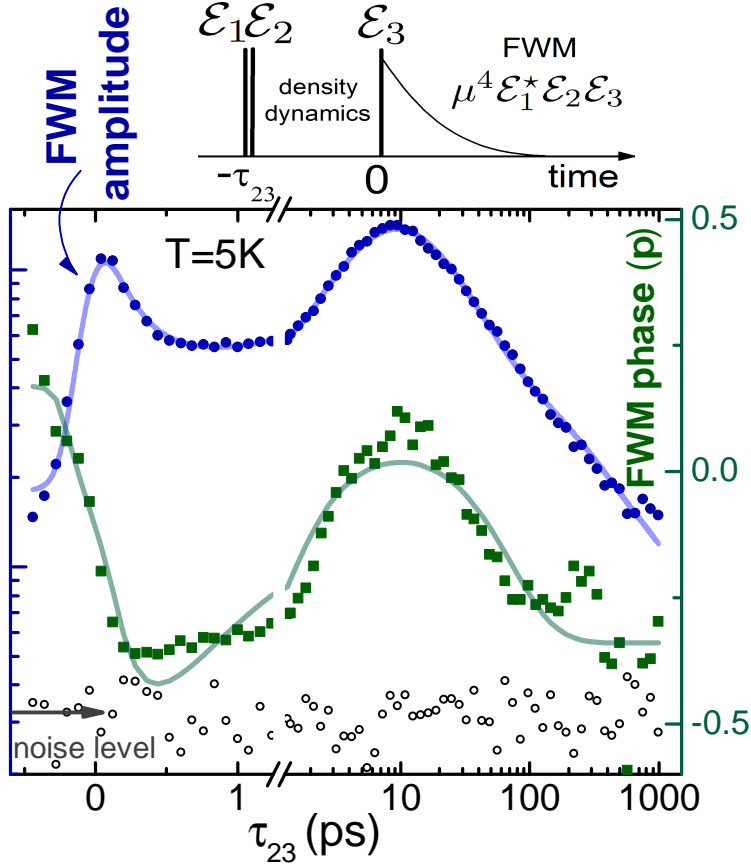


Figure 6: **Resonantly excited EX population dynamics in a h -BN/MoS₂/ h -BN heterostructure measured at 5 K.** Co-circular polarization of $\mathcal{E}_{1,2,3}$, $\tau_{12} = 0.1$ ps. The excitation power for each beam is $0.3 \mu\text{W}$. The amplitude and phase retrieved by spectral interferometry are given by blue circles and green squares, respectively, along with the simultaneous fit according to the complex trial function (see discussion in the main text). Note the complex character of the measured FWM observable, inducing interference in the amplitude and phase-shifts revealing distinct densities scattering processes, while varying τ_{23} . Top: pulse sequence employed to measure density dynamics *via* FWM. Measurement performed on the sample A.

exhibiting exponential decays with the time constants τ_n . We found that a minimum of three such processes were required for a good fit to the data at 5 K. With increasing the temperature to 40 K, inclusion of the fourth component was necessary to model the data (not shown).

Additionally, the third line of the above expression has been explicitly added to describe the power law visible for longer delays τ_{23} . Introducing this term is motivated by the observed power law in the decay for different temperatures, and the fact that after some time the EX density will be thermalized and therefore described by an overall decay process, which here appears to be EX-EX scattering leading to a power-law decay. The fitting function accounts for the temporal width of the excitation Gaussian pulses (τ_0) and their repetition period (T_r) yielding this quite involved, but analytical expression.

The simultaneously fitted dynamics to the FWM amplitude and FWM phase is shown by blue and green traces in Figure 6, respectively. We interpret it as follows. The initial drop is governed by the radiative recombination of EXs in the light cone competing with scattering out of the light cone leading to a fast decay with $\tau_1 = T_1 = (0.13 \pm 0.04)$ ps. Later dynamics is characterized by $\tau_2 = (4.2 \pm 1.4)$ ps and comparable amplitude ($A_1 \approx 0.62 \times A_2$). Populating the indirect dark EXs results in the rise of FWM amplitude and produces a phase-shift due to modified interaction with the bright EXs. This is followed by the overall density decay *via* EX-EX scattering into a photon and a bright EX or non-radiative Auger recombination. To rephrase, in this model, the FWM rise (quantified by the second process, with the parameters: τ_2 , A_2 and ϕ_2) is due to the scattering of EXs into states with a stronger interaction with the probed bright EXs, for example spin-forbidden direct or indirect EXs. We speculate that, within the TMD family, such scattering from bright towards dark EX configuration is the most efficient in MoS₂ SLs, owing to its particularly small conduction band splitting,⁴⁷ giving a reason why it is much more pronounced here with respect to MoSe₂ SLs.³⁷ After 10 ps, this process is completed and the subsequent decay dynamics is ruled by the power law with the power $\alpha = 0.59 \pm 0.05$. This value corresponds to a decay rate proportional to the EX density with the power $1 + 1/\alpha \approx 2.7 \approx 3$, and thus indicates tri-exciton scattering as dominating decay mechanism. The remaining third exponential process yields the decay constant $\tau_3 = (56 \pm 18)$ ps and $A_3 \approx 1.4 \times A_1$, comparable with A_1 . We found that, while restricting the modeling to the first two decay processes one can describe the FWM amplitude dynamics reasonably well (not shown), the third decay process was necessary to fit the phase dynamics. This exemplifies how the phase observable contains additional information, otherwise obscured when considering the FWM amplitude only. This third process is tentatively attributed to a further redistribution between the different dark exciton states, as suggested by the different phase of the resulting interaction.

Parameter	Value	Error	Physical meaning
A_{of}	19059	1573	amplitude of the complex offset
φ_{of}	0.666	0.136	phase of the complex offset
A_{nr}	52443	10184	two-photon absorption amplitude
φ_{nr}	0.261	0.288	phase of the two-photon absorption process
τ_0	0.16	0	$(2 \ln 2)^{-1}$ of autocorrelation (intensity FWHM) in ps
T_r	13157	0	laser repetition time in ps
A_1	167700	59863	amplitude of the 1 st process
τ_1	0.132	0.041	time constant for the 1 st process in ps
A_2	269940	68166	amplitude 2 nd process
τ_2	4.22	1.27	time constant for the 2 nd process in ps
A_3	232748	88908	amplitude of the 3 rd process
τ_3	55.81	17.85	time constant for the 3 rd process in ps
φ_1	-0.442	0.231	phase of the 1 st process in rad
φ_2	-2.696	0.067	phase of the 2 nd process in rad
φ_3	0.784	0.243	phase of the 3 rd process in rad
A_p	134112	90948	amplitude of the power law decay
φ_p	-1.20626	0.09495	phase of the power law decay in rad
γ_p	0.056	0.066	coefficient in the power law
α	0.59	0.05	exponent of the power law

Table 1. Set of parameters for the fit shown in Figure 6 using the response function (1). The values marked in blue correspond to the most relevant physical parameters of the fit.

Conclusions. We have shown that encapsulating MoS₂ SLs in between *h*-BN layers drastically improves the optical quality in this material and permits to recover giant coherent nonlinear responses of the EXs, as expected from their oscillator strength. Using two heterostructures differing in the degree of the EX disorder, we have performed three-beam FWM to infer the EX coherent and incoherent dynamics, spanning timescales from 100 fs to 1.3 ns. By measuring the coherence dynamics and time-resolved FWM, we reveal the formation of the photon echos, extracting homogeneous γ and inhomogeneous σ contributions to the EX spectral line-shape. We directly show the correlation between σ and the measured initial population loss, indicating that the latter is affected by the change in radiative lifetime on top of non-radiative channels. Importantly, at some positions of the low disorder sample the FWM transient appears in the form of interaction dominated free-induction decay, with no evidence of photon echo formation, showing that the EX broadening in the probed region is homogeneous within the experimental accuracy. FWM microscopy allowed us to reveal the impact of the local disorder on the EX’s oscillator strength and line-shape. The latter is shown to be affected by the temperature and also weakly by the excitation induced dephasing due to EX-EX interaction. The EX density dynamics measured by FWM is sensitive both to the dark and the bright EX density, and can recover the complex interaction energy with the bright EXs using the amplitude and phase of the signal. Employing the modeling with complex fitting function, we identified three major EX relaxation channels, specifically: radiative decay and scattering out of the light cone (into fast EXs), scattering into dark excitons, which subsequently decay *via* tri-EX scattering. Further FWM transient grating

investigations, thoroughly addressing a large space of parameters — the temperature, injected exciton density, valley-polarization, distinct TMD SL materials (exhibiting optically bright and dark exciton ground state), as well as the charge state (neutral EXs *versus* tri-ions) — are necessary to draw a comprehensive picture of the exciton relaxation dynamics. This would enable to elaborate more accurate and predictive models, yet also more involved, with respect to the one presented in this work. To consistently describe the measured rich EX relaxation dynamics, one could for example incorporate master equations, modeling the dynamics between the different EX reservoirs.

Our methodology is well suited to accurately assess the impact of disorder on the EX responses in experiments with forthcoming TMD heterostructures. Especially, with the suppressed structural disorder, we could access and measure the coherent dynamics, mutual couplings and lifetime of the EX excited states. Finally, using spatially-resolved FWM configuration would enable to demonstrate long-range propagation of the coherence and of the exciton-polariton diffusion. The latter aspects are of utmost importance to reveal the exciton dispersion curve in optically active van der Waals structures.⁴⁸

Methods

Preparation of the MoS₂ van der Waals heterostructure. In the present two samples, A and B, the natural MoS₂ crystals were purchased from SPI and the *h*-BN crystals were obtained from NIMS, Japan. The Si/SiO₂ substrates with a 295 nm thick oxide were cleaned using acetone and isopropyl-alcohol followed by nitrogen blow dry. For the sample A (with more disorder), we used a viscoelastic stamping method for the stack preparation, while for the sample B (with less disorder) we used a pick-up technique.

For the sample A, the *h*-BN crystal was placed on a scotch tape and was mechanically exfoliated onto a Si/SiO₂ substrate whereas the MoS₂ crystal was exfoliated onto a PDMS layer. It has been already shown that large area monolayer MoS₂ flakes could be obtained by exfoliating on PDMS.⁴⁹ A large SL MoS₂ flake ($15 \times 80 \mu\text{m}^2$) was identified on PDMS based on optical contrast and was aligned and transferred onto the *h*-BN flake on Si/SiO₂ by viscoelastic stamping, which is a dry method.⁵⁰ Likewise, another *h*-BN flake exfoliated on PDMS was stamped over the monolayer MoS₂, so as to encapsulate it and to obtain a *h*-BN/MoS₂/*h*-BN van der Waals heterostructure. While this process is known to yield clean MoS₂/*h*-BN interface at the bottom, the top interface with *h*-BN may encapsulate air blisters, puddles and cracks. These may form as a result of the exerted mechanical stress, but a low amount of contaminants is expected.

For the less disordered sample B, we use the so-called PPC (polypropylene carbonate) technique. The top and bottom *h*-BN and also the MoS₂ are exfoliated onto Si/SiO₂ substrates, respectively. Monolayer MoS₂ and 15-20 nm thick *h*-BN flakes are identified using an optical microscope. Using a micron thin film of PPC polymer top *h*-BN, monolayer MoS₂ and the bottom *h*-BN are picked up one after another to form *h*-BN/MoS₂/*h*-BN heterostructure using the procedure introduced by Wang *et al.* Science (2013), vol. 342, p. 614.

Four-wave mixing microscopy. To measure coherent, resonant responses, and in particular FWM spectra, we use heterodyne spectral interferometry (HSI).^{51,52} We employ three

laser pulses generated by the Optical Parametric Oscillator (Radiantis Inspire) pumped by a Ti:Sapphire laser (Spectra-Physics, Tsunami Femto). The pulses are chirp corrected using a geometrical pulse-shaper, such that they arrive at the sample close to their Fourier limit, with around 150 fs duration. The beams are labeled $\mathcal{E}_{1,2,3}$ and are resonant with the EX transition, as displayed in Figure 1c (black trace). They are focussed on the sample with the microscope objective (NA=0.6) down to the diffraction limit. $\mathcal{E}_{1,2,3}$ are frequency upshifted by distinct radio-frequencies $\Omega_{1,2,3}$ around 80 MHz using acousto-optic deflectors. The reflectance is collected by the same objective and spectrally dispersed by an imaging spectrometer. By exploiting optical heterodyning, we select the field component proportional to the FWM polarization proportional to $\mathcal{E}_1^* \mathcal{E}_2 \mathcal{E}_3$, which is carried by the heterodyne beat note at the $(\Omega_3 + \Omega_2 - \Omega_1)$ frequency, also occurring around 80 MHz. By applying the acousto-optic downshift for this mixing frequency at the detection path, the FWM spectral interference detected by a CCD camera is observed as a non-oscillating (DC) signal. Using a defined time-ordering between signal and reference pulses, the signal is resolved in amplitude and phase using spectral interferometry,⁵³ providing the response in both spectral and temporal domain connected *via* Fourier transform. By measuring the FWM as a function of time delays τ_{12} (between \mathcal{E}_1 and \mathcal{E}_2) and τ_{23} (between \mathcal{E}_2 and \mathcal{E}_3), we gain information about the EX coherence and density dynamics, respectively.

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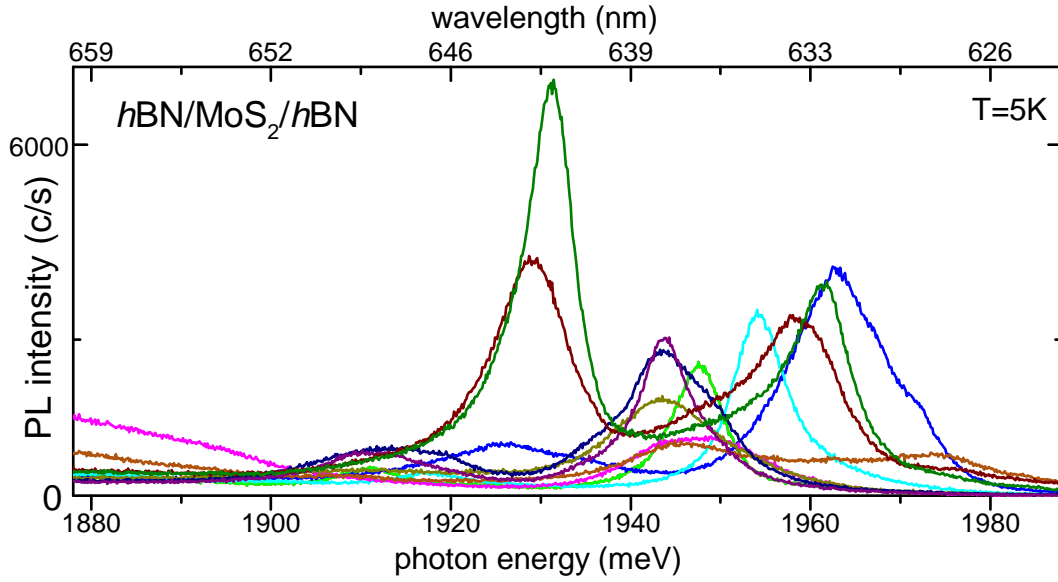
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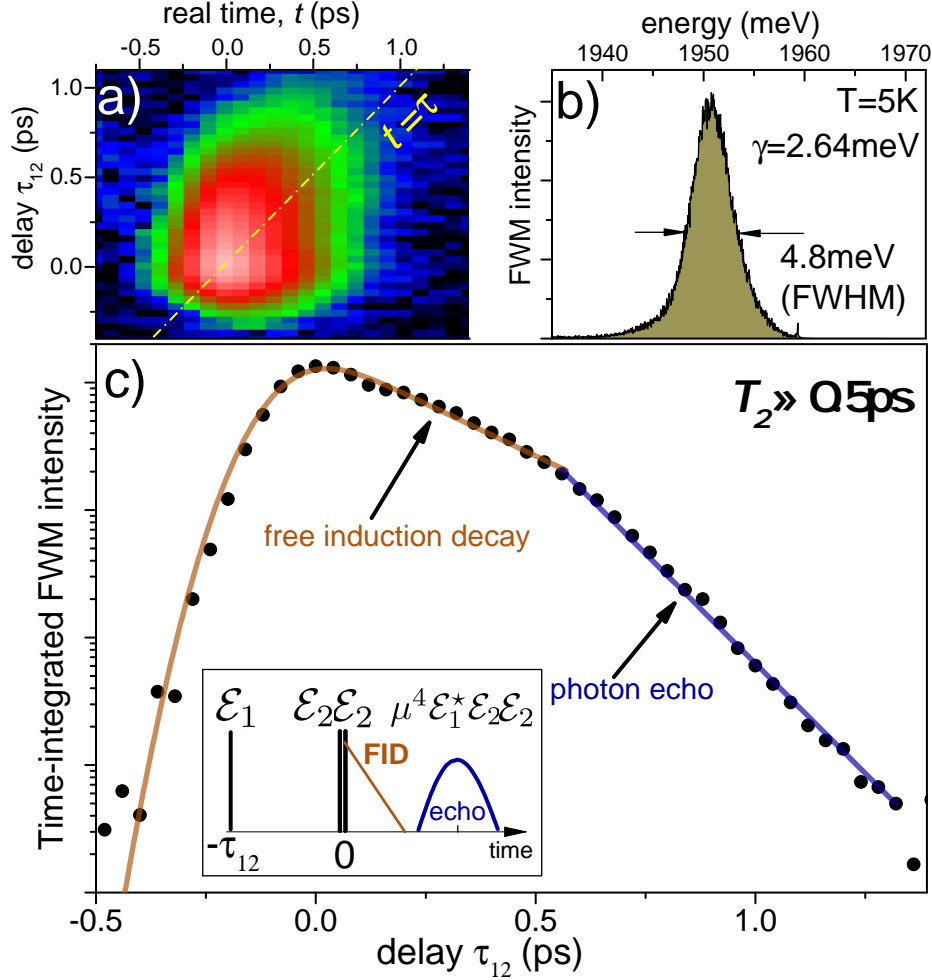
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SUPPLEMENTARY MATERIAL

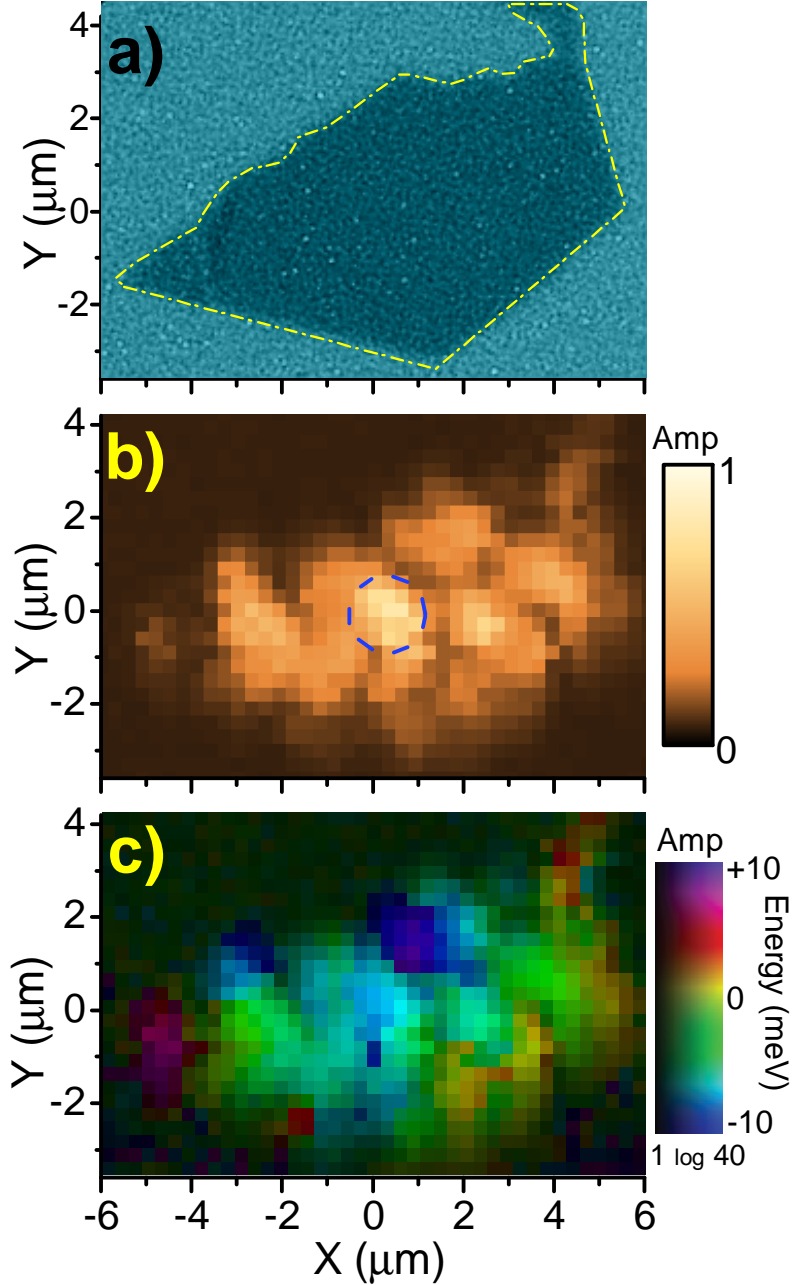
Coherence and density dynamics of excitons in a single-layer MoS₂
reaching the homogeneous limit



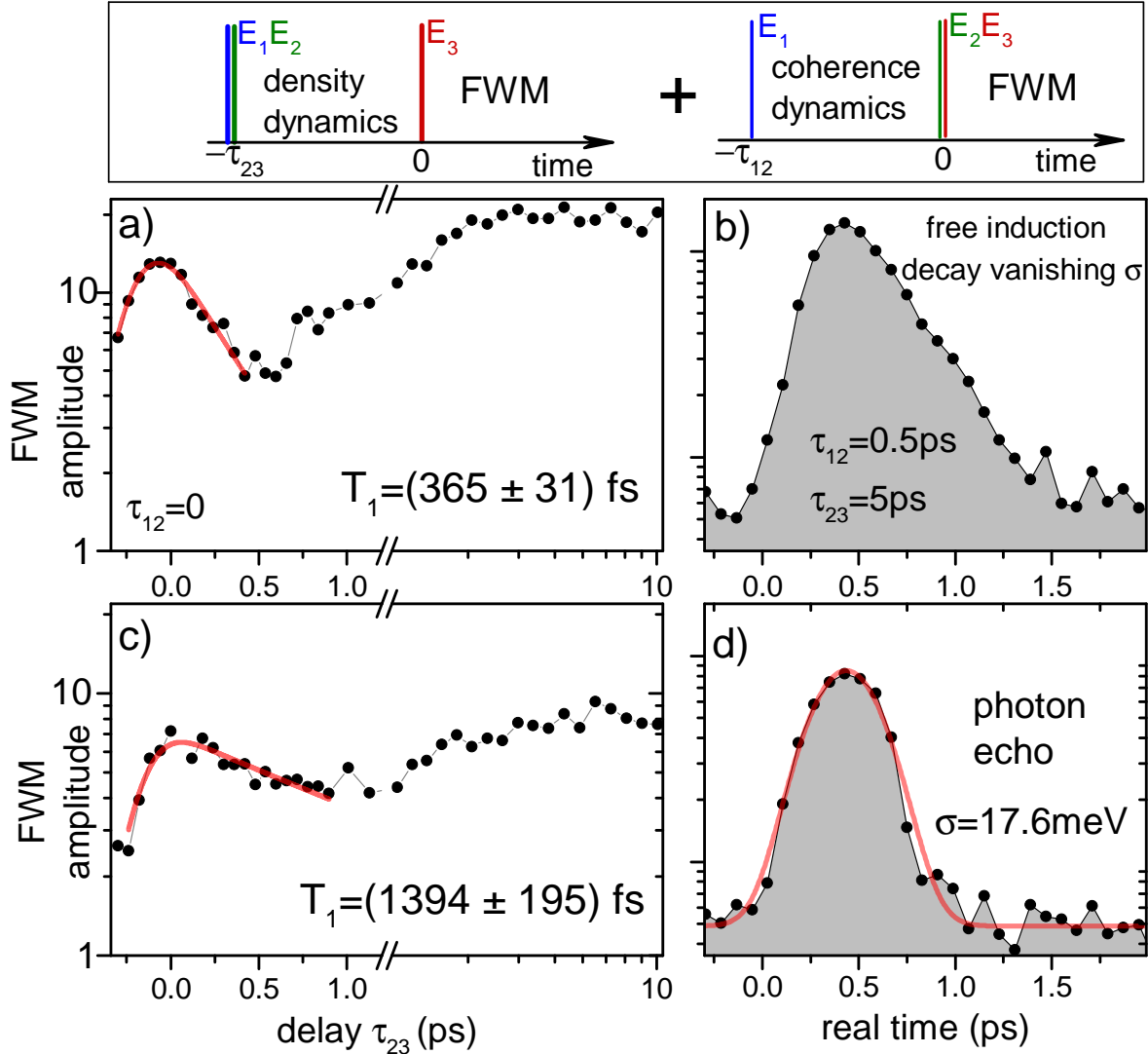
Supplementary Figure S1: **Typical photoluminescence spectra measured on the sample A, presented in Figure 1 of the main manuscript.** Note the presence of the trion transition at around 1930 meV and the appearance of the broad defect band at the low energy side at the locations of a poor optical quality.



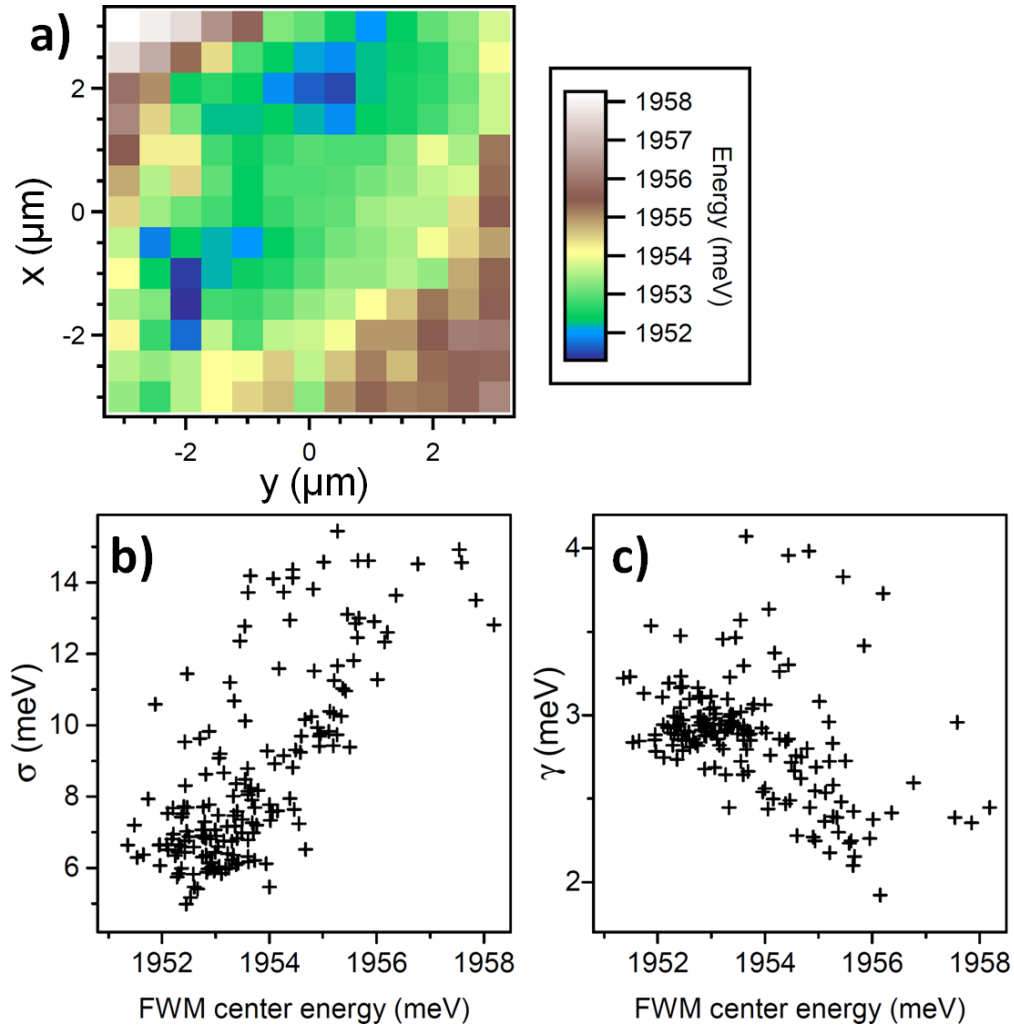
Supplementary Figure S2: **Coherence dynamics measured at the crossover towards the EX homogeneous broadening.** (a) FWM transient measured at $T=5\text{K}$ showing the transition from free induction decay (FID) to photon echo behaviour for $\tau_{12} > 0.5\text{ps}$. (b) FWM intensity measured at this spot, showing comparable homogeneous and inhomogeneous contributions to the spectral width. (c) Inset: pulse sequence employed to measure evolution of coherence via FWM spectroscopy. At short delays, the FWM transient takes a form of FID, while at longer delays the photon echo builds up. In the former case, time-integrated FWM intensity scales as $\exp(-2\tau_{12}/T_2)$, while in the latter as $\exp(-4\tau_{12}/T_2)$. This yields a bi-exponential decay of the coherence dynamics, consistently described by $T_2 \approx 500\text{fs}$.



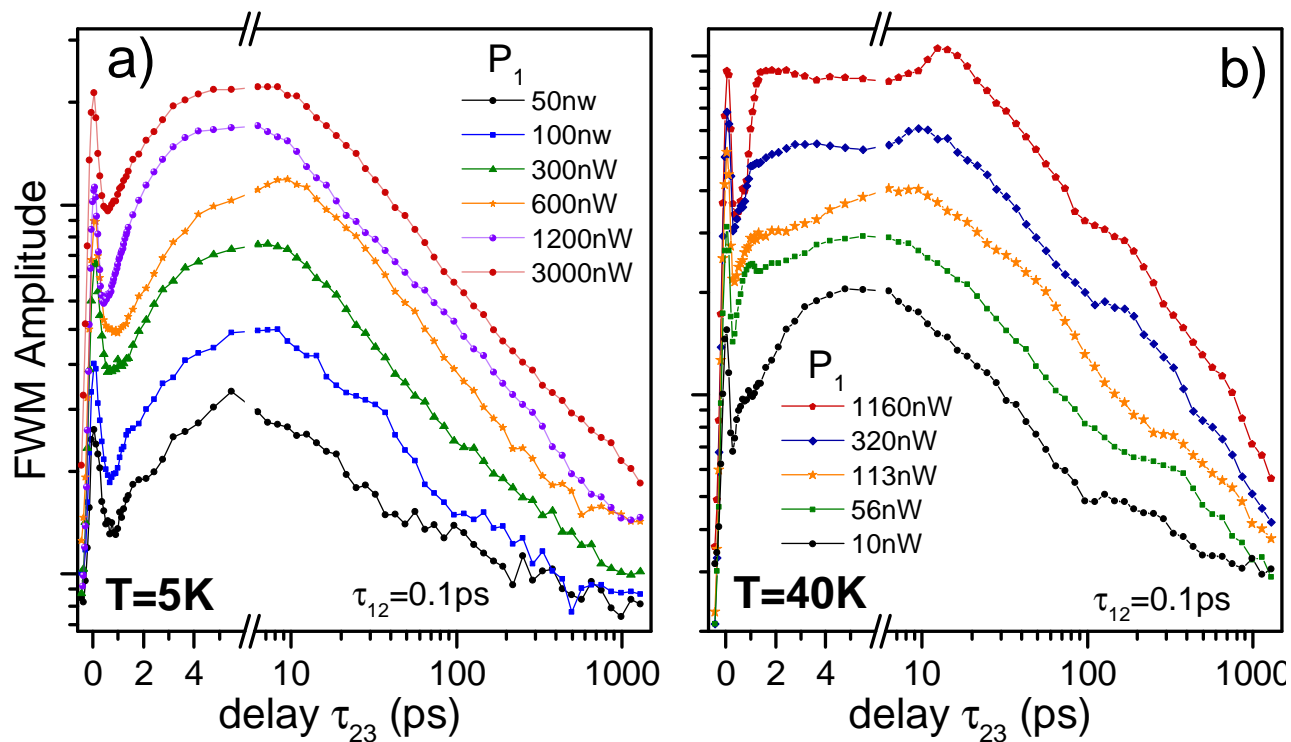
Supplementary Figure S3: **Imaging of the low-disorder heterostructure, sample B, employed in Figures 3 and 4 of the main manuscript.** (a) Optical image of the sample, prior to covering with the top h -BN layer. The shape of the MoS₂ SL is indicated with the yellow trace. (b) Spatial imaging of the FWM amplitude measured for $\tau_{12} = 0.05$ ps and $\tau_{23} = 5$ ps, $T = 4.7$ K. Data presented in the manuscript were obtained at the zone marked with a blue dashed circle. Linear color scale as indicated by the vertical bar. (c) as in (b), but amplitude and the EX center energy (relative to 1940 meV) are encoded with brightness and hue, as indicated by the vertical bar. Note the presence of the strain-induced global inhomogeneous broadening, forming patches of quasi-equal energies, suggesting formation of extended polariton states, delocalized via the motional narrowing. Within a given domain, we find micron-sized areas with suppressed disorder, yielding the homogeneously broadened EX transition.



Supplementary Figure S4: **Correlations between the initial decay of the EX density, inhomogeneous broadening σ and the oscillator strength μ .** Top: Experimentally applied sequence within the three-pulse FWM, employed to measure above correlations. Note that both measurements are executed within the same run, before stepping to the following spot on the sample, overcoming the issue of spatial drifts. A pair of measurements performed at the homogeneously (a, b) and inhomogeneously (c, d) broadened areas, respectively. Faster initial population decay and larger FWM amplitude measured in a) with respect to c) is correlated with the vanishing σ in b) and large σ in d). This directly indicates that areas of stronger disorder exhibit a longer population lifetime and a weaker μ , owing to increase of the radiative lifetime. The noise level in (a, c) is situated intersection of the axes, note the common vertical scaling in (a, c) and (b, d), respectively.



Supplementary Figure S5: **Correlations between the EX center energy, inhomogeneous σ and inhomogeneous broadening γ .** One can observe that the center energy varies within the linewidth. The center energy upshifts by the amount of σ , indicating that the disorder occurs on sub-resolution scale and has a repulsive character. The measurement performed on sample A. The figure completes Figure 5 of the main text.



Supplementary Figure S6: τ_{23} -dependence of the FWM amplitude measured at the ns timescale for different driving powers and temperatures, as indicated. **Sample A.** For all measurements, note: 1) significant increase of the FWM amplitude at the timescale of 10 ps, following the initial decay at the sub-ps scale. 2) persistence of the power-law decay at long delays. 3) Onset of additional EX relaxation pathways with increasing the temperature, reflected by increasingly more involved trace of the FWM decay. This figure is auxiliary to Figure 6 of the man text.

Graphical TOC Entry

